## GRAPHENE-BASED GAS SENSORS MODIFIED BY PULSED LASER DEPOSITION FOR NO<sub>2</sub> AND NH<sub>3</sub> DETECTION

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Graphene, due to its flat 2D structure (high surface-to-volume ratio) and electrical properties (high carrier mobility and low electrical noise) has attracted a lot of attention for gas sensor applications.

We recently demonstrated that modification of graphene and introduction of suitable defects can significantly improve its sensitivity and selectivity to different gases. Pulsed laser deposition (PLD) of ultrathin  $ZrO_2$ , Ag or  $V_2O_5$  layers on top of graphene was used to enhance its performance as a sensing material.

Graphene in this work was grown on copper foil in a hot-wall quartz tube CVD reactor and later



Fig.1 Responses of  $ZrO_2$ -modified graphene to various  $NO_2$  concentrations in air under UV illumination.

transferred onto  $Si/SiO_2$  substrates. According to Raman spectroscopy, defects were introduced in graphene only after functionalisation by PLD. Conductometric responses of graphene-based gas sensors to the polluting NO<sub>2</sub> gas in air were measured with different gas concentrations in the range between 40 ppb and 1 ppm (Fig. 1).

The response of modified graphene gas sensors was improved significantly (up to two orders) in comparison with pristine graphene. Different materials used in PLD process also allowed performance diversification:  $ZrO_2$ -modified samples had amplified responses but required UV-light illumination for signal recovery after exposure to NO<sub>2</sub> while in the case of Ag the responses were reversible without UV light. In the case of V<sub>2</sub>O<sub>5</sub> it has been demonstrated that the modified sensor became more sensitive towards reducing pollutant NH<sub>3</sub>, providing partial selectivity.

References

- 1. Berholts A., Kahro T., Floren A., Alles H., Jaaniso R., Appl.Phys.Lett. 105, 163111 (2014).
- 2. Kodu M., Berholts A., Kahro T., Avarmaa T., Kasikov A., Niilisk A., Alles H., Jaaniso R., *Appl. Phys. Lett.* 109, 113108 (2016).

